

RELIABILITY REPORT  
FOR  
MAX4430EUK+T  
PLASTIC ENCAPSULATED DEVICES

July 20, 2010

**MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR.  
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<b>Approved by</b>
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## Conclusion

The MAX4430EUK+T successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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### I. Device Description

#### A. General

The MAX4430/MAX4431 single and MAX4432/MAX4433 dual operational amplifiers feature wide bandwidth, 16-bit settling times in 37ns, and low-noise/low-distortion operation. The MAX4430/MAX4432 are compensated for unity gain stability and have a small signal -3dB bandwidth of 180MHz. The MAX4431/MAX4433 are compensated for closed-loop gains of +2 or greater and have a small-signal -3dB bandwidth of 215MHz. The MAX4430-MAX4433 op amps require only 11mA of supply current per amplifier while achieving 125dB open-loop gain. Voltage noise density is a low 2.8nV/ Hz, and provides 100dB spurious-free dynamic range (SFDR) at 1MHz. These characteristics make these op amps ideal for driving modern high-speed 14- and 16-bit analog-to-digital converters (ADCs).

These high-speed op amps feature wide output voltage swings capable of driving ADCs with  $\geq 4V$  input dynamic range and a high current output drive up to 60mA. Using a voltage feedback architecture, the MAX4430-MAX4433 meet the requirements of many applications that previously depended on current feedback amplifiers. The MAX4430/MAX4431 are available in a space-saving 5-pin SOT23 package, and the MAX4432/MAX4433 are available in an 8-pin  $\mu$ MAX® package.

**II. Manufacturing Information**

A. Description/Function:	Dual-Supply, 180MHz, 16-Bit Accurate, Ultra-Low-Distortion Op Amps
B. Process:	CB2
C. Number of Device Transistors:	
D. Fabrication Location:	Oregon
E. Assembly Location:	Malaysia, Philippines, Thailand
F. Date of Initial Production:	July 22, 2000

**III. Packaging Information**

A. Package Type:	5-pin SOT23
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-3001-0163
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	324.3°C/W
K. Single Layer Theta Jc:	82°C/W
L. Multi Layer Theta Ja:	n/a
M. Multi Layer Theta Jc:	n/a

**IV. Die Information**

A. Dimensions:	50 X 38 mils
B. Passivation:	Si <sub>3</sub> N <sub>4</sub> (Silicon nitride)
C. Interconnect:	Au
D. Backside Metallization:	None
E. Minimum Metal Width:	2 microns (as drawn)
F. Minimum Metal Spacing:	2 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO <sub>2</sub>
I. Die Separation Method:	Wafer Saw

## V. Quality Assurance Information

- A. Quality Assurance Contacts: Don Lipps (Manager, Reliability Engineering)  
Bryan Preeshl (Managing Director of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.  
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

### A. Accelerated Life Test

The results of the 150°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 160 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 6.9 \times 10^{-9}$$

$\lambda = 6.9$  F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maxim-ic.com/qa/reliability/monitor>. Cumulative monitor data for the CB2 Process results in a FIT Rate of 0.14 @ 25C and 2.48 @ 55C (0.8 eV, 60% UCL)

### B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

### C. E.S.D. and Latch-Up Testing

The OP95 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-50mA.

**Table 1**  
Reliability Evaluation Test Results

**MAX4430EUK+T**

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
<b>Static Life Test</b> (Note 1)				
	Ta = 150°C Biased Time = 192 hrs.	DC Parameters & functionality	160	0
<b>Moisture Testing</b> (Note 2)				
HAST	Ta = 130°C RH = 85% Biased Time = 96hrs.	DC Parameters & functionality	77	0
<b>Mechanical Stress</b> (Note 2)				
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality	77	0

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data